

MOSFET N-CH 600V 120MA SOT-223

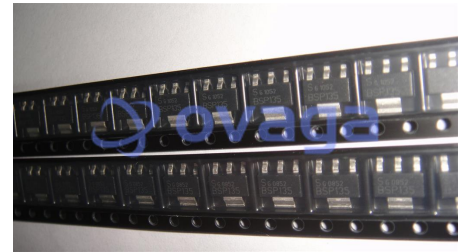
Manufacturers [Infineon Technologies Corporation](#)

Package/Case SOT223

Product Type Transistors

RoHS

Lifecycle



Images are for reference only

Please submit RFQ for BSP135L6327 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

## General Description

BSP135L6327 is a specific part number for a N-channel enhancement-mode vertical MOSFET transistor produced by Infineon Technologies.

## Features

Drain-source voltage (VDS): 240 V

Continuous drain current (ID): 0.25 A

Low on-resistance (RDS(on)): 11 ohm

Fast switching speed

Low threshold voltage



## Related Products



### [BSP613P](#)

Infineon Technologies Corporation  
SOT-223



### [BSB013NE2LXI](#)

Infineon Technologies Corporation  
WDSON-2



### [BSC030N08NS5ATMA1](#)

Infineon Technologies Corporation  
TDSON-8



### [BSC016N06NSATMA1](#)

Infineon Technologies Corporation  
DSON-8



### [BSC011N03LS](#)

Infineon Technologies Corporation  
PG-TDSON-8



### [BSC014N04LSATMA1](#)

Infineon Technologies Corporation  
tdson-8



### [BSC026N08NS5ATMA1](#)

Infineon Technologies Corporation  
TDSON-8



### [BSC066N06NSATMA1](#)

Infineon Technologies Corporation  
TDSON-8